

STTH120L04TV1

Ultrafast high voltage rectifier

Mian product characteristics

I _{F(AV)}	2 x 60 A
V _{RRM}	400 V
T _j (max)	150° C
V _F (typ)	0.83 V
t _{rr} (max)	50 ns

Features and benefits

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses
- Package insulation voltage: 2500 V_{RMS}

Description

The STTH120L04TV1 uses ST 400 V technology and is specially suited for use in switching power supplies, welding equipment, and industrial applications, as an output rectification clique.



Order codes

Part number	Marking
STTH120L04TV1	STTH120L04TV1

Table 1. Absolute ratings (limiting values, per diode)

Symbol	Parai	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage			400	٧
I _{F(RMS)}	RMS forward current			120	Α
I _{F(AV)}	$T_c = 115^{\circ} \text{ C } \delta = 0.5$ Per diode		60	Α	
FS:1	Surge non repetitive forward current t _p = 10 ms sinusoidal			600	Α
Γ_{stg}	Storage temperature range			-55 to + 150	° C
T _j	Maximum operating junction temperature			150	° C

Characteristics STTH120L04TV1

1 Characteristics

Table 2. Thermal resistance

Symbol	Parameter		Value (max).	Unit
В	lunation to coop	Per diode	0.74	
R _{th(j-c)}	Junction to case	Total	0.42	°C/W
R _{th(c)}	Coupling		0.1	

When diodes 1 and 2 are used simultaneously:

 $\Delta \text{ Tj(diode 1)} = P(\text{diode 1}) \times R_{\text{th(j-c)}}(\text{Per diode}) + P(\text{diode 2}) \times R_{\text{th(c)}}$

Table 3. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾	Reverse leakage	T _j = 25° C	V - V			50	-114
'R'	current	T _j = 125° C	$V_R = V_{RRM}$		50	500	μА
V _E (2)	Forward voltage drop	T _j = 25° C	I _F = 60 A			1.2	V
VF. / Forward voilage drop	T _j = 150° C	IF = 00 A		0.83	1.0	V	

- 1. Pulse test: $t_p = 5$ ms, $\delta < 2\%$
- 2. Pulse test: $t_p = 380 \mu s$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

 $P = 0.8 \times I_{F(AV)} + 0.0033 I_{F^2(RMS)}$

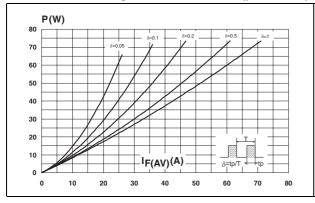
Table 4. Dynamic characteristics (per diode)

Symbol Parameter Test conditions Min Typ	Max	Unit
Reverse recovery $T_i = 25^{\circ} \text{ C}$ $I_F = 1 \text{ A} dI_F/dt = 50 \text{ A/}\mu\text{s}$ $V_R = 30 \text{ V}$ 66	90	ns
time $T_j = 25^{\circ} \text{ C}$ $I_F = 1 \text{ A } dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 30 \text{ V}$ 36	50	115
$I_{RM} \qquad \begin{array}{ c c c c c c c c c c c c c c c c c c c$	15	Α
S_{factor} Softness factor $T_j = 125^{\circ} C$ $I_F = 60 A$ $V_R = 200 V$ $I_F = 60 A$ $I_F = 6$		
$t_{fr} \qquad \begin{array}{ l l } \hline \\ \hline $	600	ns
$V_{FP} \begin{array}{ c c c c c c c c c c c c c c c c c c c$		V

STTH120L04TV1 Characteristics

Figure 1. Conduction losses versus average forward current (per diode)

Figure 2. Forward voltage drop versus forward current (per diode)



T_PM(A)

180

160

160

(Maximum values)

17,=150°C

(Typical values)

100

80

40

V_{FM}(V)

0

0.0

0.2

0.4

0.6

0.8

1.0

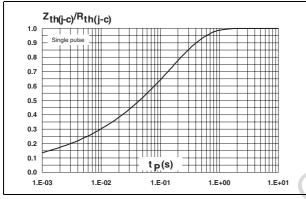
1.2

1.4

1.6

Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Figure 4. Peak reverse recovery current versus dl_F/dt (typical values, per diode)



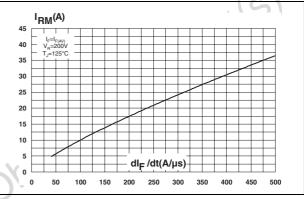
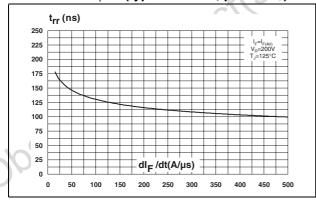
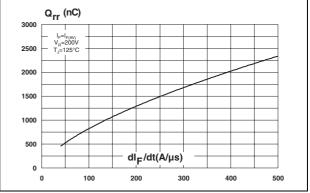


Figure 5. Reverse recovery time versus dl₋/dt (typical values, per diode)

Figure 6. Reverse recovery charges versus dl_F/dt (typical values, per diode)

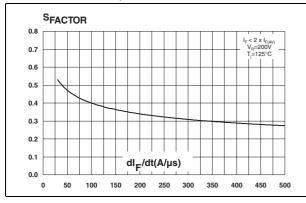




Characteristics STTH120L04TV1

Figure 7. Reverse recovery softness factor versus dl_F/dt (typical values, per diode)

Figure 8. Relative variations of dynamic parameters versus junction temperature



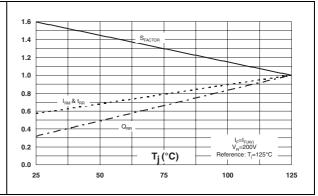
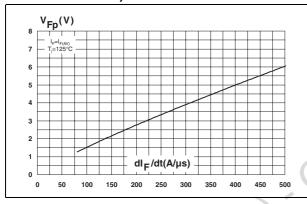


Figure 9. Transient peak forward voltage versus dl_F/dt (typical values, per diode)

Figure 10. Forward recovery time versus dI_F/dt (typical values, per diode)



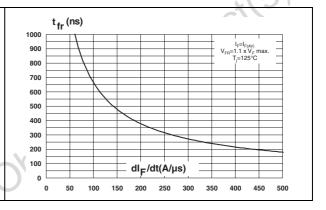
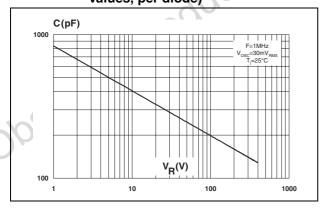


Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)



4/7

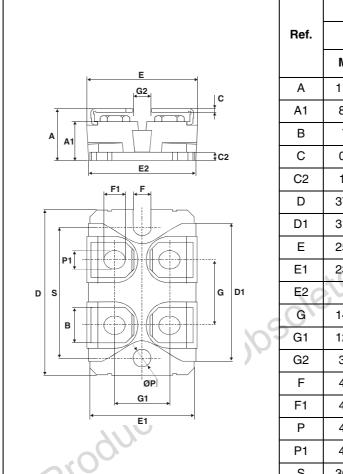
STTH120L04TV1 Package information

2 Package information

Epoxy meets UL94, V0

Cooling method: by conduction (C)

Table 5. ISOTOP Dimensions



	Dimensions				
Ref. Millimeters		neters	Inches		
	Min. Ma		Min.	Max.	
Α	11.80	12.20	0.465	0.480	
A1	8.90	9.10	0.350	0.358	
В	7.8	8.20	0.307	0.323	
С	0.75	0.85	0.030	0.033	
C2	1.95	2.05	0.077	0.081	
D	37.80	38.20	1.488	1.504	
D1	31.50	31.70	1.240	1.248	
Е	25.15	25.50	0.990	1.004	
E1	23.85	24.15	0.939	0.951	
E2	24.80 typ.		0.976 typ.		
G	14.90	15.10	0.587	0.594	
G 1	12.60	12.80	0.496	0.504	
G2	3.50	4.30	0.138	0.169	
F	4.10	4.30	0.161	0.169	
F1	4.60	5.00	0.181	0.197	
Р	4.00	4.30	0.157	0.69	
P1	4.00	4.40	0.157	0.173	
S	30.10	30.30	1.185	1.193	

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Ordering information STTH120L04TV1

3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTH120L04TV1	STTH120L04TV1	ISOTOP	27 g (without screws)	10 (with screws)	Tube

4 Revision history

	Date	Revision	Description of Changes
	11-Aug-2006	1	First issue
obsole	11-Aug-2006	Jucits	First issue PRODUCTION PRODU

6/7

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2006 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

577